

INFORMATION DISCLOSURE STATEMENT BY APPLICANT (USE SEVERAL SHEETS IF NECESSARY)	U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE	ATTY. DOCKET NO. IMEC232.001DV1	APPLICATION NO. 10/644,690
	APPLICANT Stalmans et al.		
	FILING DATE August 19, 2003	GROUP 2812	

U.S. PATENT DOCUMENTS

EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE (IF APPROPRIATE)
CL	1	4,806,996	02-1989	Luryi	—	—	
	2	4,818,337	04-1989	Barnett et al.	—	—	
	3	5,136,351	08-1992	Inoue et al.	—	—	
	4	5,397,429	03-1995	Hummel et al.	—	—	
	5	5,679,475	10-1997	Yamagata et al.	—	—	
	6	5,981,400	11-1999	Lo	—	—	
CL	7	6,194,245	02-2001	Tayanaka	—	—	

FOREIGN PATENT DOCUMENTS

EXAMINER INITIAL		DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION	
							YES	NO
CL	8	EPO 341 017 A2	05-1989	EPO	—	—		
	9	DE 43 19 413 A1	12-1994	GERMANY	—	—		
	10	DE 197 43 692 A1	04-1999	GERMANY	—	—		
	11	63182811	07-1988	JAPAN PATENT ABSTRACT	—	—		
	12	06163968	06-1994	JAPAN PATENT ABSTRACT	—	—		
	13	03042818	02-1991	JAPAN PATENT ABSTRACT	—	—		
CL	14	03235371	10-1991	JAPAN PATENT ABSTRACT	—	—		

EXAMINER INITIAL	OTHER DOCUMENTS (INCLUDING AUTHOR, TITLE, DATE, PERTINENT PAGES, ETC.)	
CL	15	Grigorás et al., ENHANCED LIGHT ABSORPTION IN ANODICALLY ETCHED SILICON WAFERS, Elsevier Science S.A., 276, pp. 228-230 (1996)
CL	16	Mauk et al., THIN SILICON SOLAR CELLS WITH INTERNAL REFLECTION AND THEIR FABRICATION BY SOLUTION GROWTH, IEEE, pp. 192-197, (1985)
CL	17	Vernon et al., HIGH PERFORMANCE POROUS SILICON SOLAR CELL DEVELOPMENT, IEEE, pp. 1583-1586 (1994)
CL	18	Zettner et al., NOVEL POROUS SILICON BACKSIDE LIGHT REFLECTOR FOR THIN SILICON SOLAR CELLS, Prog. Photovol. Res. 6, pp. 423-432 (1998)

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EXAMINER	<i>calomla</i>	DATE CONSIDERED	2/5/04
*EXAMINER: INITIAL IF CITATION CONSIDERED, WHETHER OR NOT CITATION IS IN CONFORMANCE WITH MPEP 609; DRAW LINE THROUGH CITATION IF NOT IN CONFORMANCE AND NOT CONSIDERED, INCLUDE COPY OF THIS FORM WITH NEXT COMMUNICATION TO APPLICANT.			